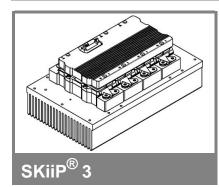
SKiiP 2013GB172-4DL



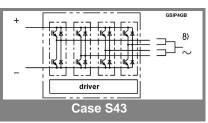
2-pack-integrated intelligent Power System

Power section SKiiP 2013GB172-4DL

Data

Power section features

- · SKiiP technology inside
- Trench IGBTs
- CAL diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiiP[®] 3 System)
- IEC 60068-1 (climate) 40/125/56
- UL recognized file no. E63532
- with assembly of suitable MKP capacitor per terminal
- 8) AC connection busbars must be connected by the user; copper busbars available on request



Absolute	Maximum Ratings	s = 25°C unless otherwise specified				
Symbol	Conditions	Values	Units			
IGBT						
V_{CES}		1700	V			
V _{CES} V _{CC} 1)	Operating DC link voltage	1200	V			
V_{GES}		± 20	V			
I _C	T _s = 25 (70) °C	2000 (1500)	Α			
Inverse diode						
I _F = - I _C	T _s = 25 (70) °C	1650 (1250)	Α			
I _{FSM}	$T_j = 150 ^{\circ}\text{C}, t_p = 10 \text{ms}; \text{sin}$	13500	Α			
I²t (Diode)	Diode, T _j = 150 °C, 10 ms	911	kA²s			
T _j , (T _{stg})		- 40 + 150 (125)	°C			
V _{isol}	rms, AC, 1 min, main terminals to heat sink	4000	V			
I _{AC-terminal}	per AC terminal, rms, T _s = 70 °C,	400	Α			
	T _{terminal} <115 °C					

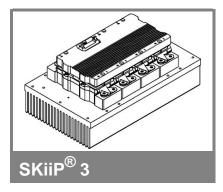
Characteristics					T _s = 25°C unless otherwise specified			
Symbol	Conditions				min.	typ.	max.	Units
IGBT	_							_
V _{CEsat}	I _C = 1200 A measured at te	A, T _j = 25 erminal	(125) °C;			1,9 (2,2)	2,4	V
V_{CEO}	T _i = 25 (12					1 (0,9)	1,2 (1,1)	V
r _{CE}	$T_j = 25 (12)$					0,8 (1)	1 (1,3)	mΩ
I _{CES}	$V_{GE} = 0 V,$ $T_{j} = 25 (12)$		ES'			4,8 (288)		mA
E _{on} + E _{off}	I _C = 1200 A	A, V _{CC} = 9	00 V			780		mJ
	T _j = 125 °C	C, V _{CC} = 1	200 V			1150		mJ
R _{CC+EE} ,	terminal ch	ip, T _i = 25	5 °C			0,13		mΩ
L _{CE}	top, bottom	ı ´				3		nH
C _{CHC}	per phase,	AC-side				6,8		nF
Inverse o	diode							
$V_F = V_{EC}$	I _F = 1200 A measured at te	A, T _j = 25 (erminal	(125) °C			2 (1,8)	2,15	V
V_{TO}	T _i = 25 (12	5) °C				1,1 (0,8)	1,2 (0,9)	V
r _T	$T_i = 25 (12)$	5) °C				0,8 (0,8)	0,8 (0,9)	mΩ
E _{rr}	$I_{\rm C} = 1200 A$	A, V _{CC} = 9	00 V			144		mJ
	$T_{j} = 125 ^{\circ}C$	$V_{CC} = 1$	200 V			171		mJ
Mechani	cal data				_			_
M _{dc}	DC termina				6		8	Nm
M _{ac}	AC termina				13		15	Nm
W	SKiiP® 3 S	ystem w/c	heat sink			3,1		kg
W	heat sink					9,7		kg
						SKF16B- mperature		
60747-15		SIIIK, I	ICICIC	iice to bi	unt-m tei	iiperatuit	5 3611301 (acc.icc
$R_{th(j-s)l}$	per IGBT						0,015	K/W
R _{th(j-s)D}	per diode						0,029	K/W
Z _{th}	R _i (mK/W) (max. values)			tau _i (s)				
_	1	2	3	4	1	2	3	4
Z _{th(j-r)I}	5,6	6	6,4	0	363	0,18	0,04	1
∠ _{th(j-r)D}	10	8,4	14,8	14,8	50	5	0,25	0,04
$Z_{th(r-a)}$	3,1	17,3	3,7	0,9	230	78	13	0,4

^{*} The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of

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2-pack-integrated intelligent Power System

2-pack integrated gate driver SKiiP 2013GB172-4DL

Data

Gate driver features

- · CMOS compatible inputs
- · Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- Interlock of top/bottom switch
- · Isolation by transformers
- Fibre optic interface (option for GB-types only)
- IEC 60068-1 (climate) 40/85/56
- UL recognized file no. 242581

Absolute	Maximum Ratings	_a = 25°C unless otherwise specified		
Symbol	Conditions	Values	Units	
V_{S2}	unstabilized 24 V power supply	30	V	
V_{i}	input signal voltage (high)	15 + 0,3	V	
dv/dt	secondary to primary side	75	kV/μs	
V_{isollO}	input / output (AC, rms, 2s)	4000	V	
V _{isoIPD}	partial discharge extinction voltage, rms, Q _{PD} ≤10 pC;	1500	V	
V _{isol12}	output 1 / output 2 (AC, rms, 2s)	1500	V	
f _{sw}	switching frequency	7	kHz	
f _{out}	output frequency for I _{peak(1)} =I _C	7	kHz	
$T_{op} (T_{stg})$	operating / storage temperature	- 40 + 85	°C	

Characte	eristics	(T _a = 25°0			= 25°C)
Symbol	Conditions	min.	typ.	max.	Units
V_{S2}	supply voltage non stabilized	13	24	30	V
I _{S2}	V _{S2} = 24 V	430+45*f/kHz+0,00011*(I _{AC} /A) ²			mA
V_{iT+}	input threshold voltage (High)			12,3	V
V_{iT-}	input threshold voltage (Low)	4,6			V
R _{IN}	input resistance		10		kΩ
C _{IN}	input capacitance		1		nF
$t_{\rm d(on)IO} \\ t_{\rm d(off)IO} \\ t_{\rm pERRRESET}$	input-output turn-on propagation time input-output turn-off propagation time error memory reset time		1,3 1,3 9		μs μs μs
t _{TD}	top / bottom switch interlock time		3,3		μs
I _{analogOUT}	max.5mA; 8 V corresponds to 15 V supply voltage for external components		2000		Α
I _{s1out}	max. load current			50	mA
I _{TRIPSC} T_{tp} U_{DCTRIP}	over current trip level (I _{analog} OUT = 10 V) over temperature protection U _{DC} -protection (U _{analog OUT} = 9 V);	110	2500 not	120	A °C V
	(option for GB types)	İ	implemented		

For electrical and thermal design support please use SEMISEL.

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